



查询KRC103S供应商

SEMICONDUCTOR TECHNICAL DATA

KOREA ELECTRONICS CO.,LTD.

捷多邦，专业PCB打样工厂，24小时加急出货

KRC101S ~

KRC106S

EPITAXIAL PLANAR NPN TRANSISTOR

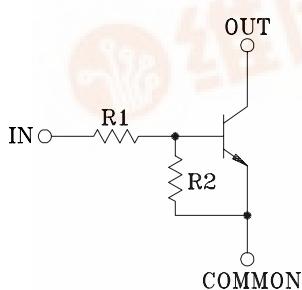
SWITCHING APPLICATION.

INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

FEATURES

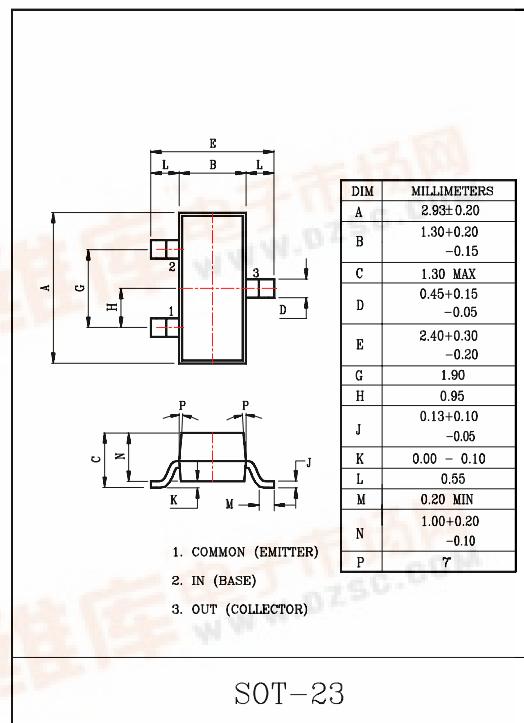
- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.

EQUIVALENT CIRCUIT



BIAS RESISTOR VALUES

TYPE NO.	R1(kΩ)	R2(kΩ)
KRC101S	4.7	4.7
KRC102S	10	10
KRC103S	22	22
KRC104S	47	47
KRC105S	2.2	47
KRC106S	4.7	47



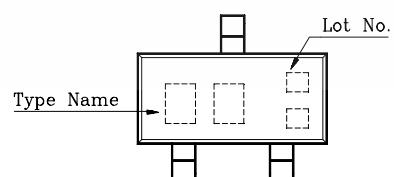
MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Voltage	KRC101S ~106S	V _O	50	V
Input Voltage	KRC101S	V _I	20, -10	V
	KRC102S		30, -10	
	KRC103S		40, -10	
	KRC104S		40, -10	
	KRC105S		12, -5	
	KRC106S		20, -5	
Output Current	KRC101S ~106S	I _O	100	mA
Power Dissipation		P _D	200	mW
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	-55~150	°C

MARK SPEC

TYPE	KRC101S	KRC102S	KRC103S	KRC104S	KRC105S	KRC106S
MARK	NA	NB	NC	ND	NE	NF

Marking



KRC101S ~ KRC106S

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Cut-off Current	KRC101S ~ 106S	I _{O(OFF)}	V _O =50V, V _I =0	-	-	500	nA
DC Current Gain	KRC101S	G _I	V _O =5V, I _O =10mA	30	55	-	
	KRC102S			50	80	-	
	KRC103S			70	120	-	
	KRC104S			80	200	-	
	KRC105S			80	200	-	
	KRC106S			80	200	-	
Output Voltage	KRC101S ~ 106S	V _{O(ON)}	I _O =10mA, I _I =0.5mA	-	0.1	0.3	V
Input Voltage (ON)	KRC101S	V _{I(ON)}	V _O =0.2V, I _O =5mA	-	1.5	2.0	V
	KRC102S			-	1.8	2.4	
	KRC103S			-	2.1	3.0	
	KRC104S			-	2.8	5.0	
	KRC105S			-	0.8	1.1	
	KRC106S			-	0.9	1.3	
Input Voltage (OFF)	KRC101S ~ 104S	V _{I(OFF)}	V _O =5V, I _O =0.1mA	1.0	1.2	-	V
	KRC105S ~ 106S			0.5	0.65	-	
Transition Frequency	KRC101S ~ 106S	f _T *	V _O =10V, I _O =5mA	-	200	-	MHz
Input Current	KRC101S	I _I	V _I =5V	-	-	1.8	mA
	KRC102S			-	-	0.88	
	KRC103S			-	-	0.36	
	KRC104S			-	-	0.18	
	KRC105S			-	-	3.6	
	KRC106S			-	-	1.8	

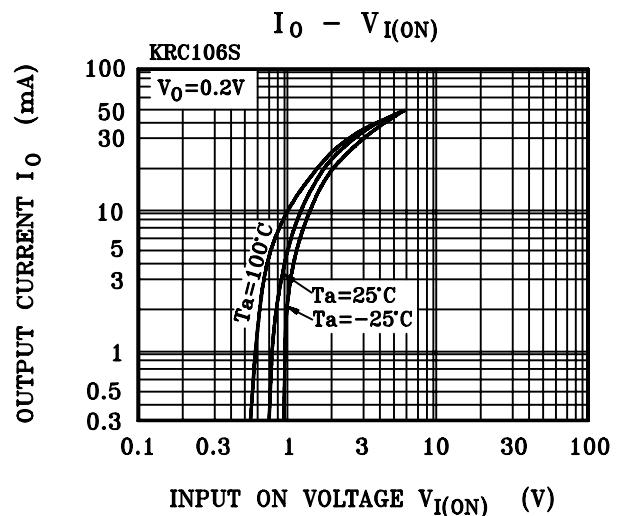
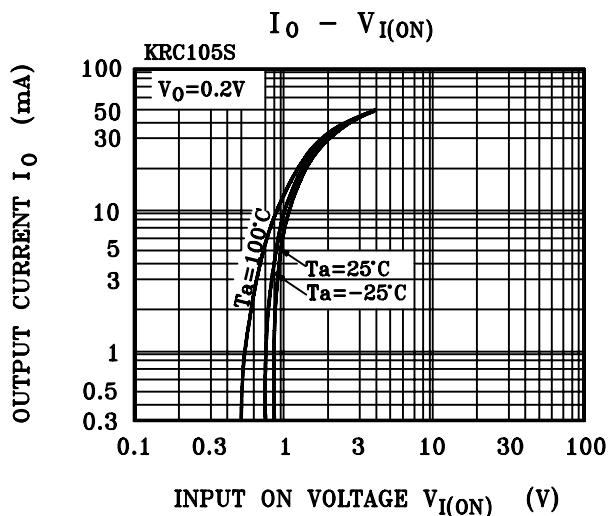
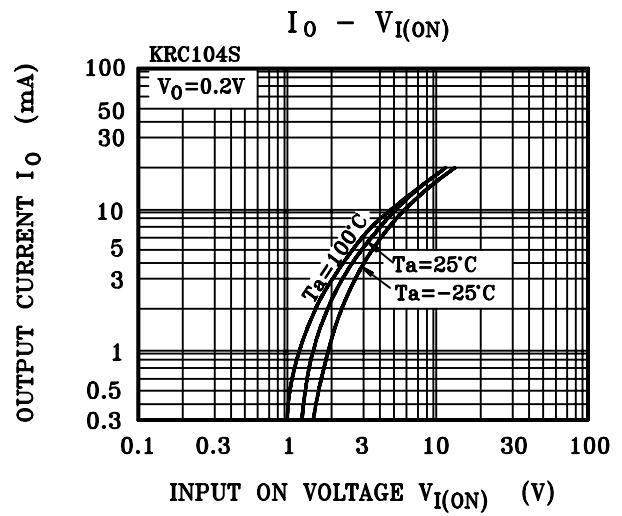
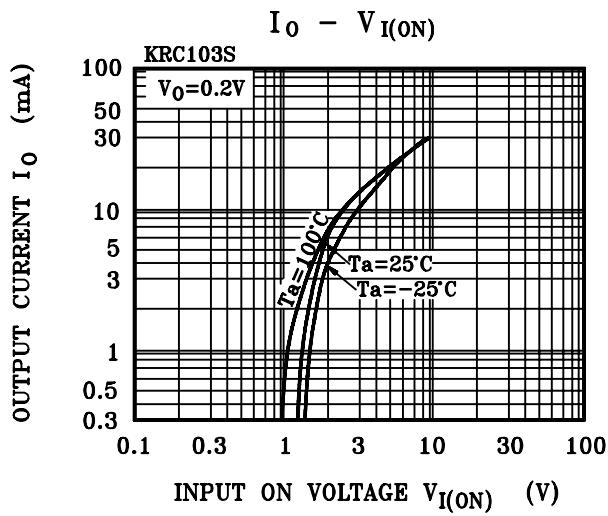
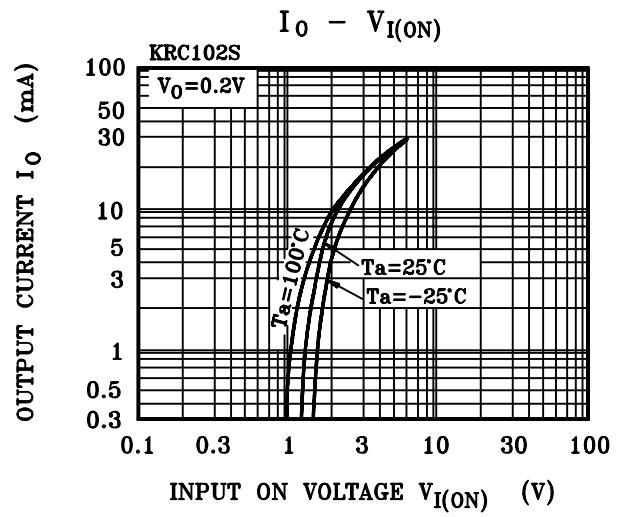
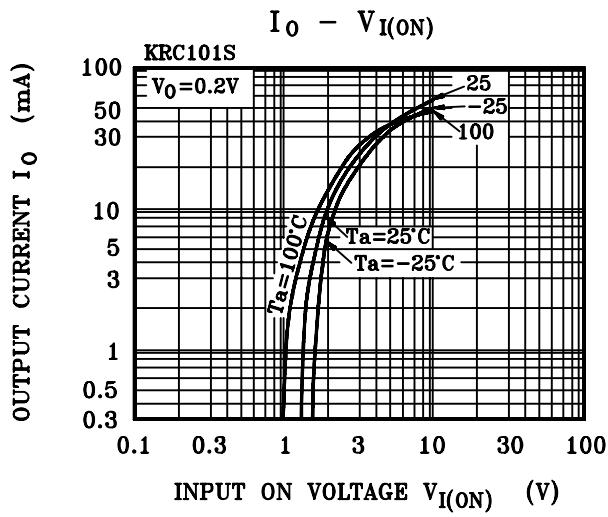
Note : *Characteristic of Transistor Only

KRC101S~KRC106S

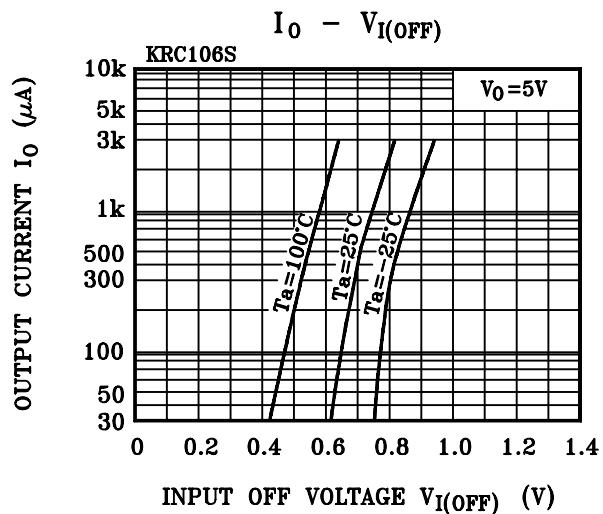
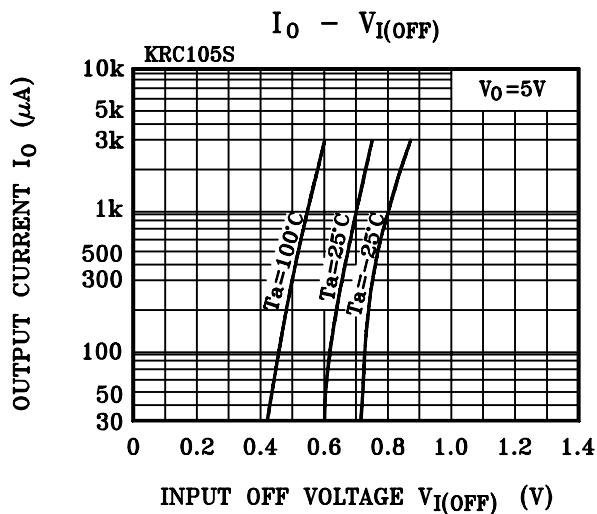
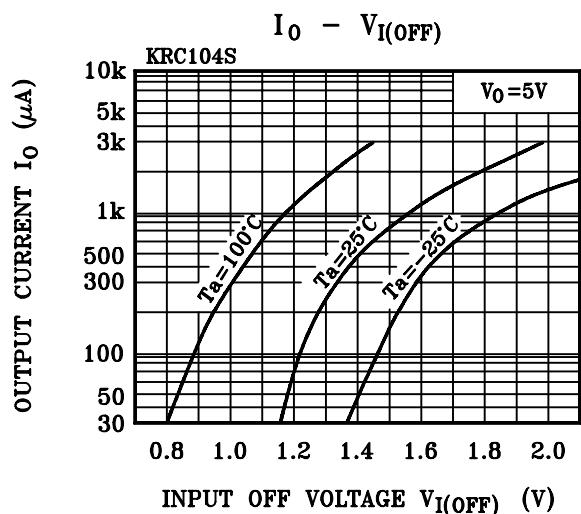
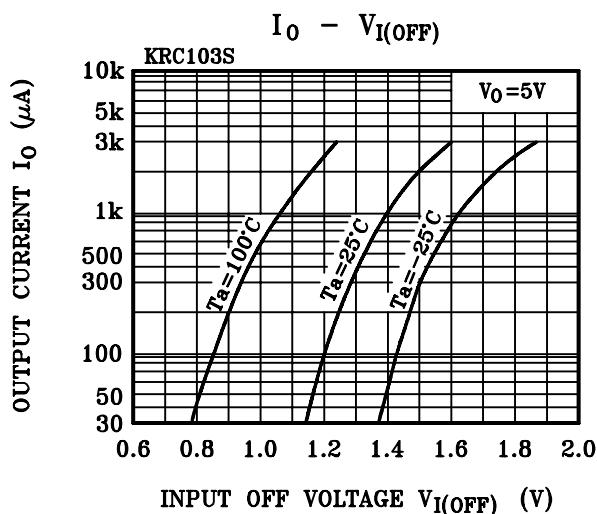
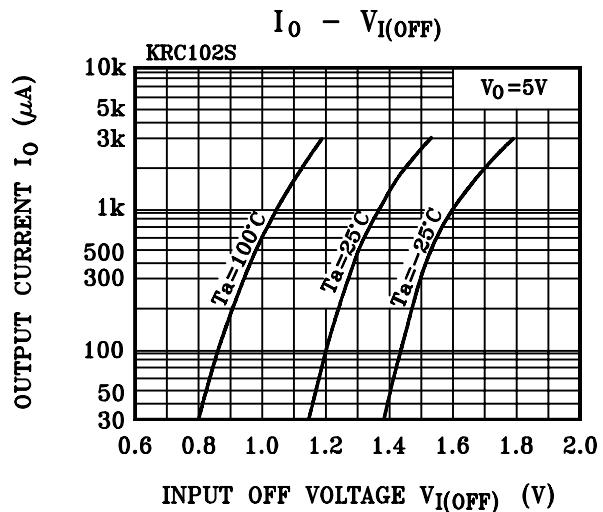
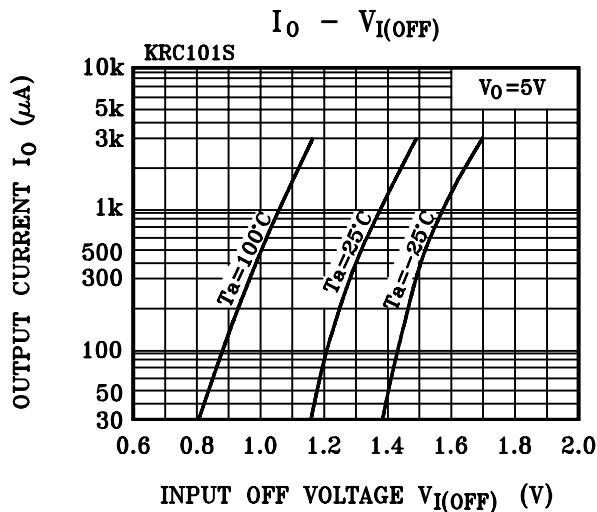
ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Switching Time	Rise Time	KRC101S	t_r	-	0.03	-	μs
		KRC102S		-	0.05	-	
		KRC103S		-	0.12	-	
		KRC104S		-	0.22	-	
		KRC105S		-	0.01	-	
		KRC106S		-	0.03	-	
	Storage Time	KRC101S	t_{stg}	-	2.0	-	
		KRC102S		-	2.0	-	
		KRC103S		-	2.0	-	
		KRC104S		-	2.0	-	
		KRC105S		-	2.0	-	
		KRC106S		-	2.0	-	
	Fall Time	KRC101S	t_f	-	0.12	-	
		KRC102S		-	0.36	-	
		KRC103S		-	0.35	-	
		KRC104S		-	0.6	-	
		KRC105S		-	0.1	-	
		KRC106S		-	0.19	-	

KRC101S ~ KRC106S



KRC101S ~ KRC106S



KRC101S ~ KRC106S

